

Avionics Band RF Power LDMOS FET

The high power transistor part number ILD1011M1000HV is designed for Avionics systems operating at 1030 MHz. Operating at 50µs, 2% pulse conditions this LDMOS FET device supplies a minimum of 1000 watts of power at 1030 MHz. All devices are 100% screened for large signal RF parameters.



Silicon LDMOS FET

- High Power Gain
- Superior thermal stability

Class AB Operation

- Gate biased to $I_{DQ} = 60$ mA

Configuration

- Common Source

Gold Metal

- Maximum Reliability

Package

- Thermally enhanced
- Pb-free and RoHS-compliant

Epoxy Sealed Lid

- Gross Leak Qualified

RF Test Fixture

- Broadband
- Matched to 50 ohms
- Long-term Correlation
- 100% Device RF Screening
- No External Tuning required

TYPICAL DATA

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Lot/SN	Freq (MHz)	P _i (W)	I _D (A)	RL (dB)	P _o (W)	Nd' (%)	G (dB)	VSWR	
								2:1	20:1
D5191-3	1030	30	50	15	1080	46.0	15.56	S	P

Pulse format = 50µs, 2% I_{DQ} = 60mA, V_d=50V

MAXIMUM RATINGS

Screen	Parameter	Symbol	Min	Max	Units	Test Conditions
BD	Drain-Source Voltage	V_{DS}	--	70	V	--
BD	Gate-Source Voltage	V_{GS}	--	20	V	--
BD	Storage Temperature Range	T_{STG}	-55	+200	°C	--
BD	Operating Junction Temperature Range	T_J	-55	+200	°C	--
Note	Screen 'BD' = parameter qualified By Design.					

THERMAL CHARACTERISTICS

Screen	Parameter	Symbol	Min	Max	Units	Test Conditions
BD	Thermal Resistance	$R_{TH(JC)}$	--	0.02	°C/W	$V_D=50V, I_{DQ}=60mA, T_F=25\pm 5^\circ C, P_{OUT}=1000W$
Note	Screen 'BD' = parameter qualified By Design.					

PROCESSING SPECIFICATIONS

Screen	Parameter	Symbol	Min	Max	Units	Test Conditions
100%	DC Wafer Probe	--	--	--	--	Per Integra specification.
Q1	Wafer DC and RF Qualification	--	--	--	--	Per Integra specification.
LM	Wire Bond Strength	--	--	--	--	Line monitor per Integra specification.
100%	Pre-cap visual inspection	--	--	--	--	Per Integra specification
100%	Gross leak test	--	--	--	--	MIL-STD-750D, Method 1071, Test Condition C
Note	Screen 'Q1' = parameter is qualified by assembly and test of 3 pieces minimum per wafer.					
Note	Screen 'LM' = parameter is qualified by assembly line monitor.					

DC ELECTRICAL CHARACTERISTICS

Screen	Parameter	Symbol	Min	Max	Units	Test Conditions
100%	Drain-Source Breakdown Voltage	BV_{DSS}	100		V	$I_D = 60mA, V_{GS} = 0V, T_F = 25\pm 5^\circ C$
BD	Drain Leakage Current	I_{DSS}		50	μA	$V_{DS} = 50V, V_{GS} = 0V, T_F = 25\pm 5^\circ C$
100%	Gate Threshold Voltage	V_{GSTH2}	2.5	10	V	$I_D = 60mA, T_F = 25\pm 5^\circ C, V_{DS} = 5V$

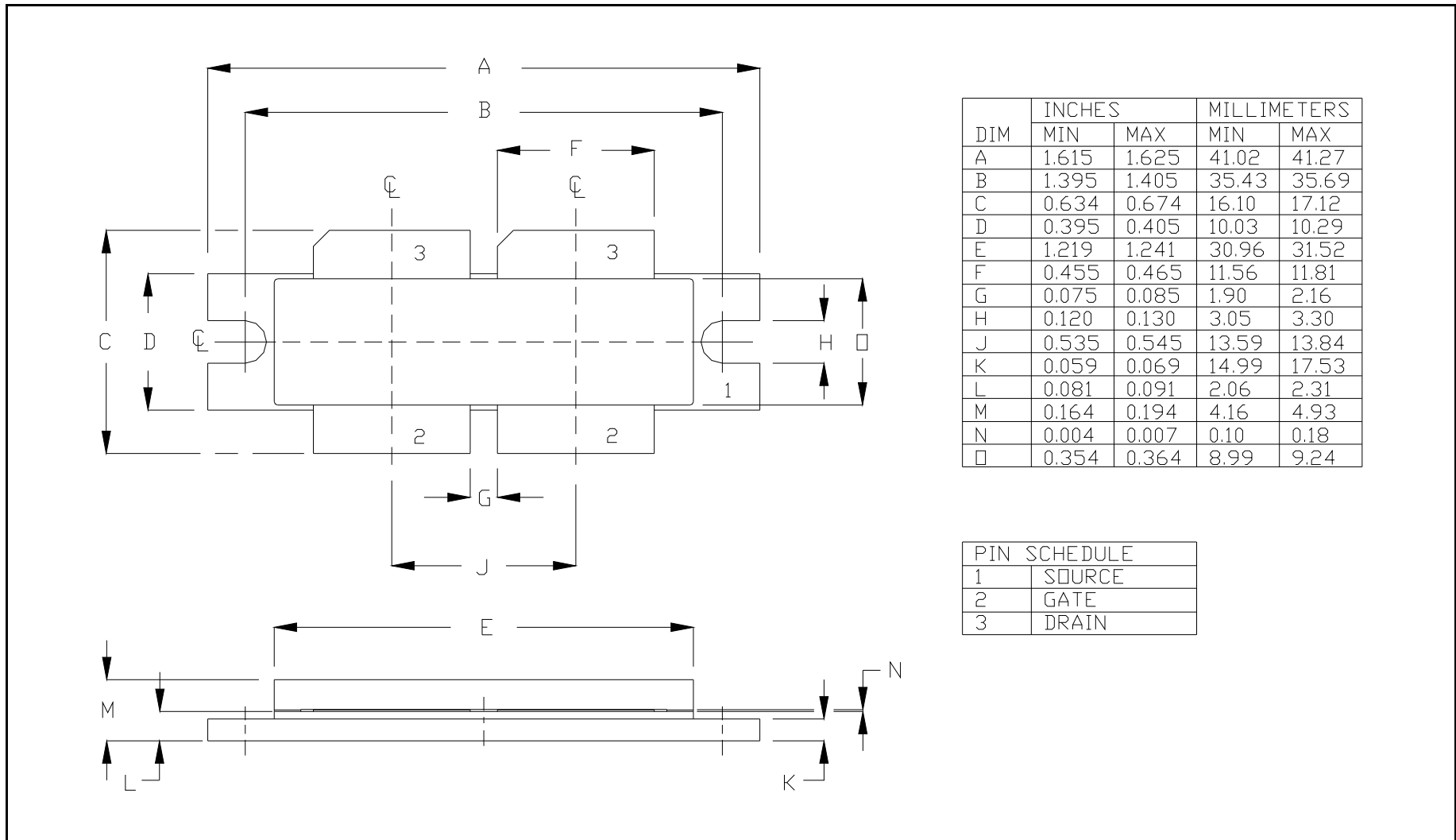
RF ELECTRICAL CHARACTERISTICS

Screen	Parameter	Symbol	Min	Max	Units	Test Conditions
100%	Input Return Loss	IRL	10	--	dB	$V_{DD}=50V$, $P_{in}=30W$, Pulse=50 μ s, 2%, $T_F=25\pm 5^\circ C$, $F=F1$, $I_{DQ}=60mA$.
BD	Maximum Overdrive	$P_{IN(MAX)}$	--	45	W	$V_{DD}=50V$, Pulse=50 μ s, 2%, $T_F=25\pm 5^\circ C$, $F=F1$, $I_{DQ}=60mA$.
100%	Power Gain	G_P	15.23	16.73	dB	$V_{DD}=50V$, $P_{in}=30W$, Pulse=50 μ s, 2%, $T_F=25\pm 5^\circ C$, $F=F1$, $I_{DQ}=60mA$.
100%	Output Power	P_{out}	1000	1413	W	$V_{DD}=50V$, $P_{in}=30W$, Pulse=50 μ s, 2%, $T_F=25\pm 5^\circ C$, $F=F1$, $I_{DQ}=60mA$.
100%	Drain Efficiency	N'_d	40	75	%	$V_{DD}=50V$, $P_{in}=30W$, Pulse=50 μ s, 2%, $T_F=25\pm 5^\circ C$, $F=F1$, $I_{DQ}=60mA$.
100%	Pulse Amplitude Droop	D	-0.5	+0.5	dB	$V_{DD}=50V$, $P_{in}=30W$, Pulse=50 μ s, 2%, $T_F=25\pm 5^\circ C$, $F=F1$, $I_{DQ}=60mA$.
100%	Stability into 2:1 VSWR	VSWR-S		2:1	--	$V_{DD}=50V$, $P_{in}=30W$, Pulse=50 μ s, 2%, $T_F=25\pm 5^\circ C$, $F=F1$, $I_{DQ}=60mA$. Rotate 2:1 output VSWR through 360° phase. No oscillatory or pulse break-up characteristics allowed on detected output pulse.
BD	Load Mismatch Tolerance	LMT		20:1	--	$V_{DD}=50V$, $P_{in}=30W$, Pulse=50 μ s, 2%, $T_F=25\pm 5^\circ C$, $F=F1$, $I_{DQ}=60mA$. Rotate 20:1 output VSWR through 360° phase. Survival.
BD	Pulse Risetime	RT		60	ns	$V_{DD}=50V$, $P_{in}=30W$, Pulse=50 μ s, 2%, $T_F=25\pm 5^\circ C$, $F=F1$, $I_{DQ}=60mA$. Measure between 10% and 90% detected power points.
Note 1	F1 = 1030MHz.					
Note 2	Pulse format = 50 μ s, 2%					
Note 3	T_F = Device flange temperature.					
Note 4	Screen 'BD' = parameter qualified By Design.					

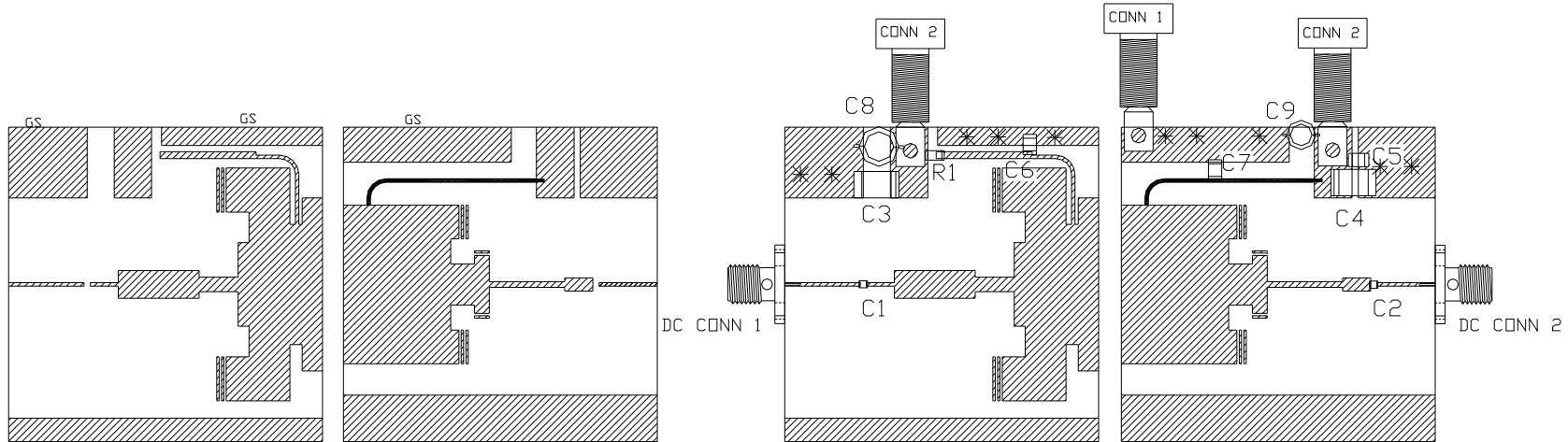
RF TEST FIXTURE IMPEDANCE CHARACTERISTICS

Frequency (MHz)	$Z_{IF} (\Omega)$	$Z_{OF} (\Omega)$
1030	0.86 + j0.34	0.30 + j0.40
Impedance Definition		

PACKAGE DIMENSIONAL OUTLINE DRAWING

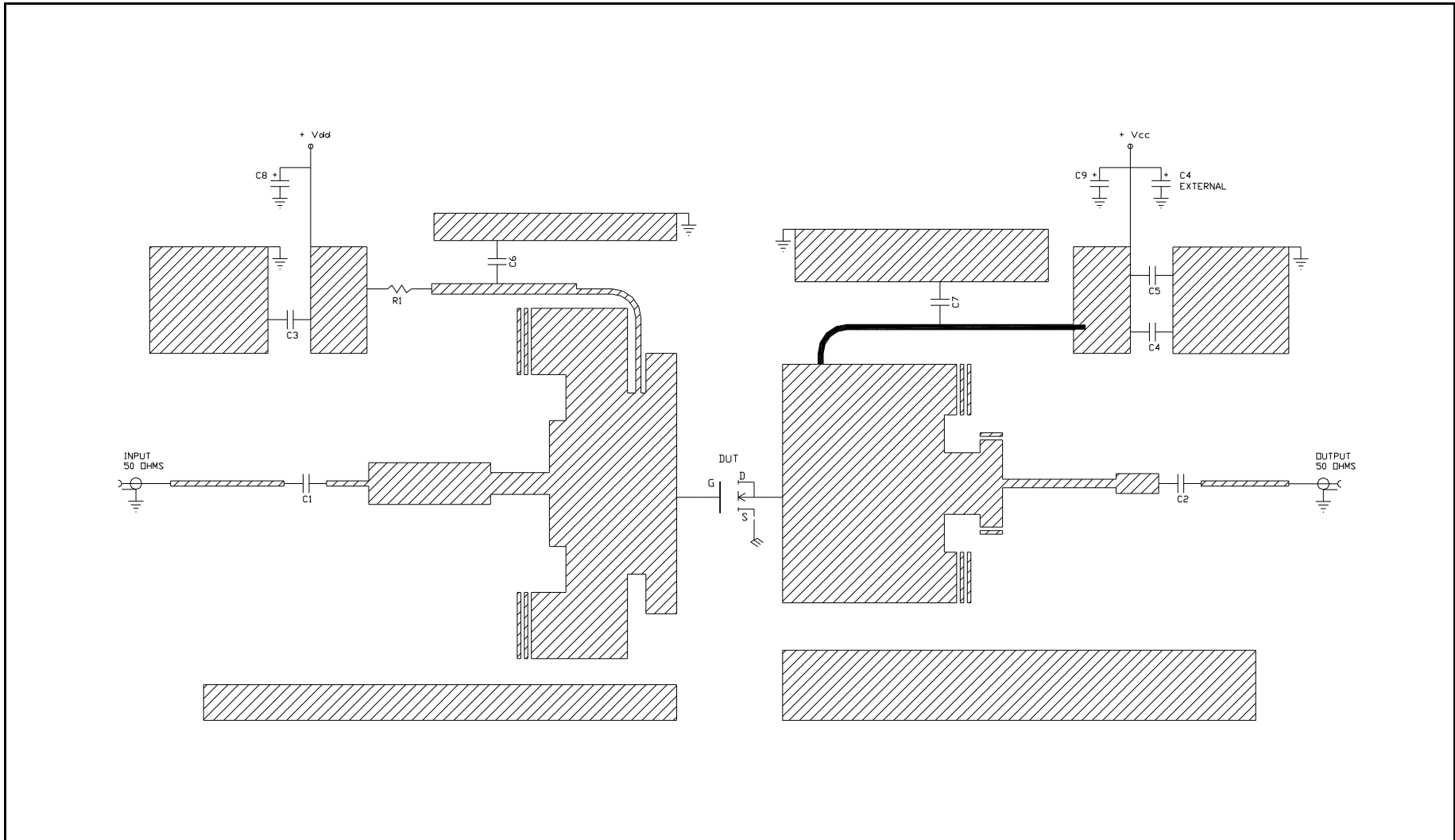


RF TEST FIXTURE – ASSEMBLY AND PARTS LIST



COMPONENT	DESCRIPTION
DUT	TRANSISTOR #ILD1011M1000HV MOUNT HARD TO THE RIGHT
PC BOARD	ROGERS #RD 3010 10.2 .025" 1oz
C1, C2	CHIP CAPACITOR ATC100A - pF
C3, C4	TANTALUM - AVX 4.7uF, 50V ESR = 0.3DHMS
C5	CERAMIC CHIP CAP 1000pF 250V
C6, C7	CHIP CAPACITOR ATC100B - 47pF
C8, C9	ELECTROLYTIC CAPACITOR, 68uF / 63V
C10 (NOT SHOWN)	ELECTROLYTIC CAPACITOR, 4700uF / 50V
R1	RESISTOR 1206 - 300DHMS
GS	GROUND SHIM, COPPER, TH=0.001"
CONN 1, CONN 2	SMA CONNECTOR, DS #2052-5636-02
INPUT PC BOARD CARRIER	2 INCH BRASS-07 (2.0")
OUTPUT PC BOARD CARRIER	2 INCH BRASS-07 (2.0")
TRANSISTOR CARRIER	2 INCH COPPER-27
TRANSISTOR CLAMP	NDRYL CLAMP-09
ALUMINUM HEAT SINK	2 INCH HEATSINK-11
DC CONN 1	BANANA JACK, BLACK
DC CONN 2	BANANA JACK, RED
NOTE	FIXTURE HARDWARE DRAWINGS AVAILABLE ON REQUEST USE CORMELL DUBILIER ALUMINUM FLAT PACK 'MLP' SERIES OR SIMILAR FOR STORAGE CAPACITOR.

RF TEST FIXTURE – ELECTRICAL SCHEMATIC



DEFINITIONS

Data Sheet Status	
Proposed Specification	This data sheet contains proposed specifications.
Preliminary Specification	This data sheet contains specifications based on preliminary measurements and data.
Product Specification	This data sheet contains final product specifications.
Maximum Ratings	
Stress above one or more of the maximum ratings may cause permanent damage to the device. These are maximum ratings only. Operation of the device at these or at any other conditions above those given in the characteristics sections of the specification is not implied. Exposure to maximum values for extended periods of time may affect device reliability.	

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